

64K (8K x 8) CMOS EPROM

FEATURES

- High speed performance
 - 120 ns access time available
- CMOS Technology for low power consumption
 - 20 mA Active current
 - 100 μ A Standby current
- Factory programming available
- Auto-insertion-compatible plastic packages
- Auto ID aids automated programming
- Separate chip enable and output enable controls
- High speed "express" programming algorithm
- Organized 8K x 8: JEDEC standard pinouts
 - 28-pin Dual-in-line package
 - 32-pin PLCC Package
 - 28-pin SOIC package
 - Tape and reel
- Available for the following temperature ranges
 - Commercial: 0°C to +70°C
 - Industrial: -40°C to +85°C

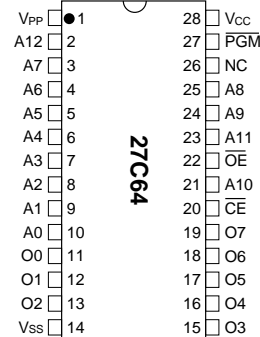
DESCRIPTION

The Microchip Technology Inc. 27C64 is a CMOS 64K bit (electrically) Programmable Read Only Memory. The device is organized as 8K words by 8 bits (8K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 120 ns. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

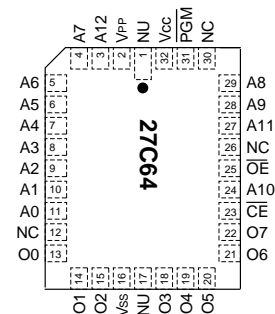
A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages.

PACKAGE TYPES

DIP/SOIC



PLCC



1.0 ELECTRICAL CHARACTERISTICS

1.1 Maximum Ratings*

VCC and input voltages w.r.t. VSS -0.6V to + 7.25V

VPP voltage w.r.t. VSS during programming -0.6V to +14V

Voltage on A9 w.r.t. VSS -0.6V to +13.5V

Output voltage w.r.t. VSS -0.6V to VCC +1.0V

Storage temperature -65°C to +150°C

Ambient temp. with power applied -65°C to +125°C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
\overline{CE}	Chip Enable
\overline{OE}	Output Enable
\overline{PGM}	Program Enable
VPP	Programming Voltage
O0 - O7	Data Output
VCC	+5V Power Supply
VSS	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

VCC = +5V ($\pm 10\%$) Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C							
Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions
Input Voltages	all	Logic "1" Logic "0"	V _{IH} V _{IL}	2.0 -0.5	VCC+1 0.8	V V	
Input Leakage	all	—	I _{LI}	-10	10	μ A	V _{IN} = 0 to VCC
Output Voltages	all	Logic "1" Logic "0"	V _{OH} V _{OL}	2.4	0.45	V V	I _{OH} = -400 μ A I _{OL} = 2.1 mA
Output Leakage	all	—	I _{LO}	-10	10	μ A	V _{OUT} = 0V to VCC
Input Capacitance	all	—	C _{IN}	—	6	pF	V _{IN} = 0V; Tamb = 25°C; f = 1 MHz
Output Capacitance	all	—	C _{OUT}	—	12	pF	V _{OUT} = 0V; Tamb = 25°C; f = 1 MHz
Power Supply Current, Active	C I	TTL input TTL input	I _{CC1} I _{CC2}	— —	20 25	mA mA	VCC = 5.5V; VPP = VCC; f = 1 MHz; $\overline{OE} = \overline{CE} = V_{IL}$; I _{OUT} = 0 mA; V _{IL} = -0.1 to 0.8V; V _{IH} = 2.0 to VCC; Note 1
Power Supply Current, Standby	C I all	TTL input TTL input CMOS input	I _{CC(s)} — —	— — —	2 3 100	mA mA μ A	$\overline{CE} = VCC \pm 0.2V$
I _{PP} Read Current VPP Read Voltage	all all	Read Mode Read Mode	I _{PP} VPP	VCC-0.7	100 VCC	μ A V	VPP = 5.5V

* Parts: C=Commercial Temperature Range; I=Industrial Temperature Range.

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

		AC Testing Waveform:		V _{IH} = 2.4V and V _{IL} = 0.45V; V _{OH} = 2.0V V _{OL} = 0.8V									
		Output Load:		1 TTL Load + 100 pF									
		Input Rise and Fall Times:		10 ns									
		Ambient Temperature:		Commercial:				T _{amb} = 0°C to +70°C					
				Industrial:				T _{amb} = -40°C to +85°C					
Parameter	Sym	27C64-12		27C64-15		27C64-17		27C64-20		27C64-25		Units	Conditions
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
Address to Output Delay	t _{ACC}	—	120	—	150	—	170	—	200	—	250	ns	$\overline{CE} = \overline{OE} = V_{IL}$
\overline{CE} to Output Delay	t _{CE}	—	120	—	150	—	170	—	200	—	250	ns	$\overline{OE} = V_{IL}$
\overline{OE} to Output Delay	t _{OE}	—	65	—	70	—	70	—	75	—	100	ns	$\overline{CE} = V_{IL}$
\overline{CE} or \overline{OE} to O/P High Impedance	t _{OFF}	0	50	0	50	0	50	0	55	0	60	ns	
Output Hold from Address \overline{CE} or \overline{OE} , whichever occurs first	t _{OH}	0	—	0	—	0	—	0	—	0	—	ns	

FIGURE 1-1: READ WAVEFORMS

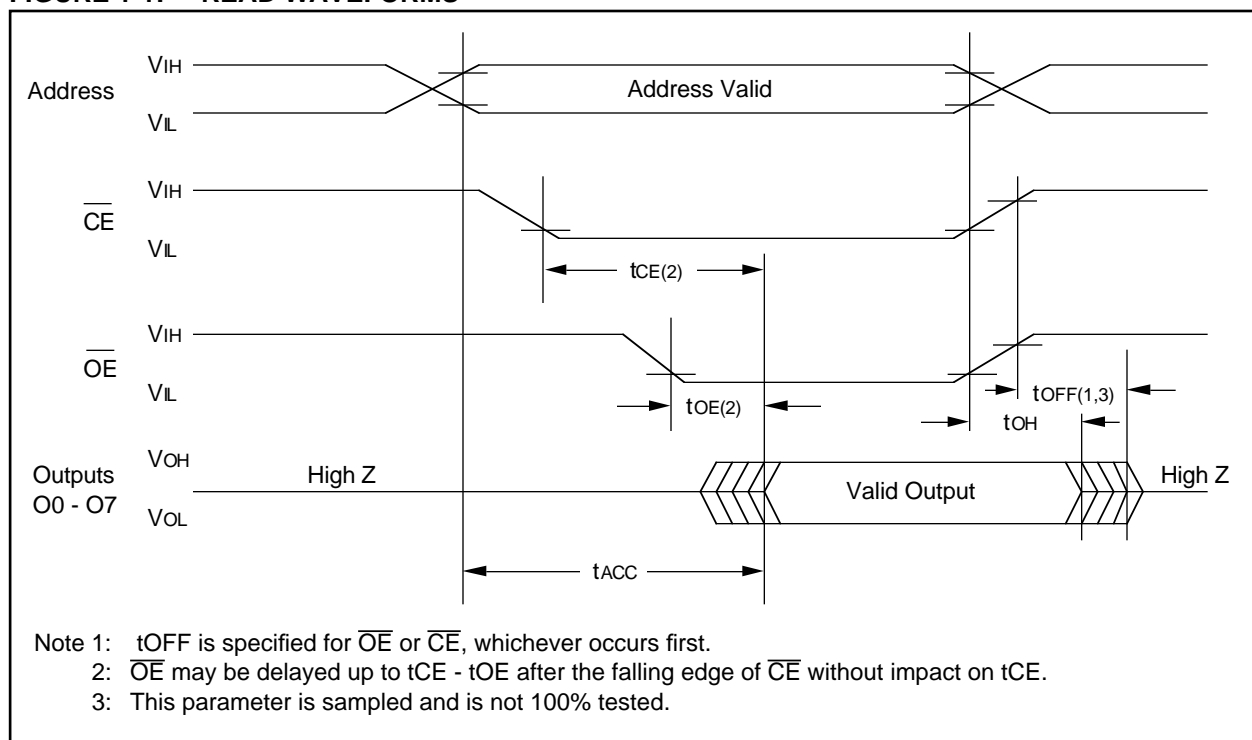


TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

Ambient Temperature: $T_{amb} = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$ $V_{CC} = 6.5\text{V} \pm 0.25\text{V}$, $V_{PP} = V_H = 13.0\text{V} \pm 0.25\text{V}$						
Parameter	Status	Symbol	Min	Max.	Units	Conditions
Input Voltages	Logic"1" Logic"0"	V_{IH} V_{IL}	2.0 -0.1	$V_{CC}+1$ 0.8	V V	
Input Leakage	—	I_{LI}	-10	10	μA	$V_{IN} = 0\text{V to } V_{CC}$
Output Voltages	Logic"1" Logic"0"	V_{OH} V_{OL}	2.4 —	— 0.45	V V	$I_{OH} = -400\text{ }\mu\text{A}$ $I_{OL} = 2.1\text{ mA}$
V_{CC} Current, program & verify	—	I_{CC2}	—	20	mA	Note 1
V_{PP} Current, program	—	I_{PP2}	—	25	mA	Note 1
A9 Product Identification	—	V_H	11.5	12.5	V	

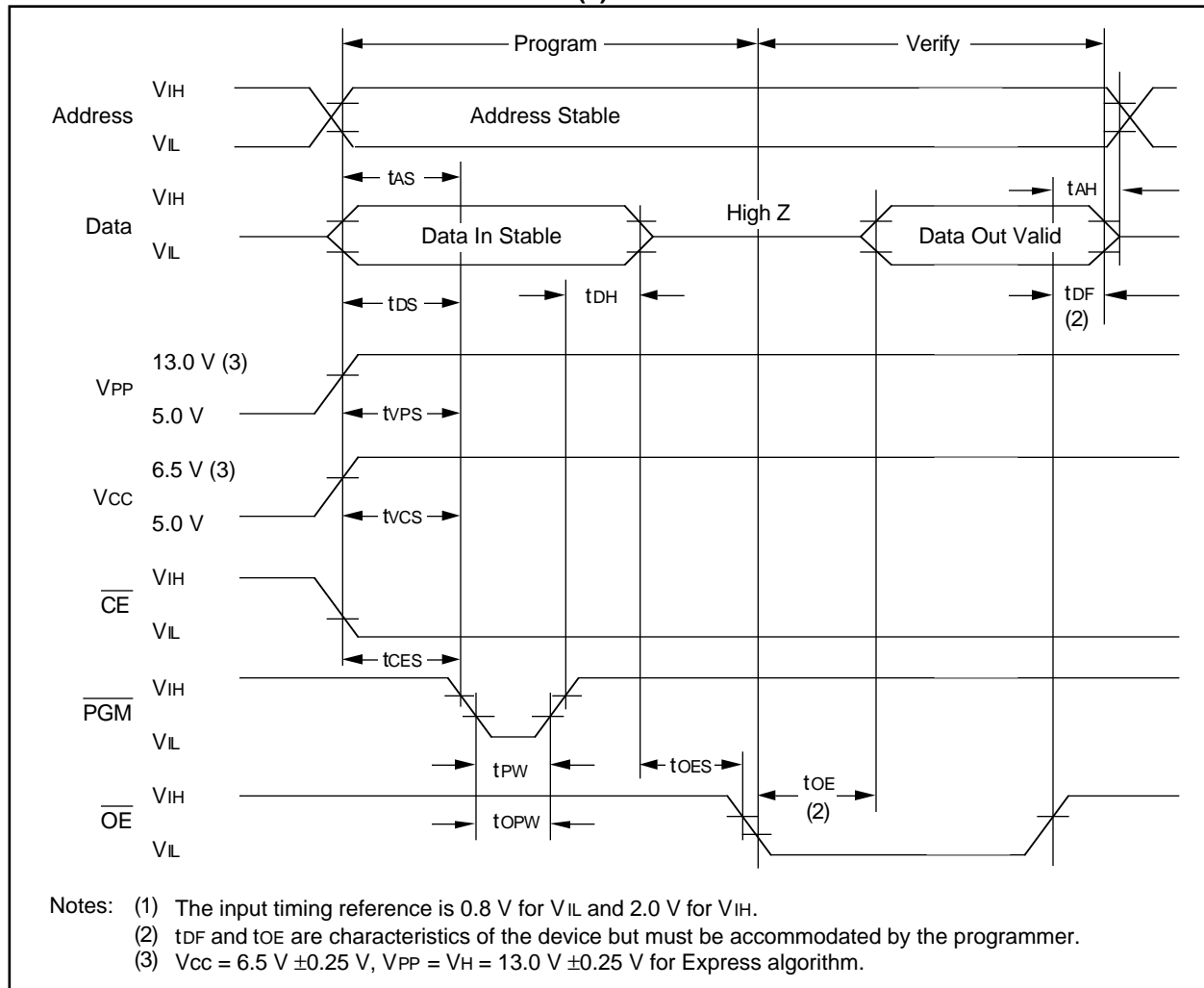
Note 1: V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .

TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit Modes	AC Testing Waveform: $V_{IH}=2.4V$ and $V_{IL}=0.45V$; $V_{OH}=2.0V$; $V_{OL}=0.8V$ Ambient Temperature: $T_{amb}=25^{\circ}C \pm 5^{\circ}C$ $V_{CC}= 6.5V \pm 0.25V$, $V_{PP} = V_H = 13.0V \pm 0.25V$				
Parameter	Symbol	Min	Max	Units	Remarks
Address Set-Up Time	tAS	2	—	μs	
Data Set-Up Time	tDS	2	—	μs	
Data Hold Time	tDH	2	—	μs	
Address Hold Time	tAH	0	—	μs	
Float Delay (2)	tDF	0	130	ns	
VCC Set-Up Time	tVCS	2	—	μs	
Program Pulse Width (1)	tPW	95	105	μs	100 μs typical
\overline{CE} Set-Up Time	tCES	2	—	μs	
\overline{OE} Set-Up Time	tOES	2	—	μs	
VPP Set-Up Time	tVPS	2	—	μs	
Data Valid from \overline{OE}	tOE	—	100	ns	

Note 1: For express algorithm, initial programming width tolerance is 100 $\mu\text{s} \pm 5\%$.

2: This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

FIGURE 1-2: PROGRAMMING WAVEFORMS (1)**TABLE 1-6: MODES**

Operation Mode	\overline{CE}	\overline{OE}	\overline{PGM}	V_{PP}	A9	O0 - O7
Read	V_{IL}	V_{IL}	V_{IH}	V_{CC}	X	DOUT
Program	V_{IL}	V_{IH}	V_{IL}	V_H	X	DIN
Program Verify	V_{IL}	V_{IL}	V_{IH}	V_H	X	DOUT
Program Inhibit	V_{IH}	X	X	V_H	X	High Z
Standby	V_{IH}	X	X	V_{CC}	X	High Z
Output Disable	V_{IL}	V_{IH}	V_{IH}	V_{CC}	X	High Z
Identity	V_{IL}	V_{IL}	V_{IH}	V_{CC}	V_H	Identity Code

X = Don't Care

1.2 Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- the \overline{CE} pin is low to power up (enable) the chip
- the \overline{OE} pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (t_{ACC}) is equal to the delay from \overline{CE} to output (t_{CE}). Data is transferred to the output after a delay from the falling edge of \overline{OE} (t_{OE}).

1.3 Standby Mode

The standby mode is defined when the \overline{CE} pin is high (V_{IH}) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100 μ A.

1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

- The \overline{OE} and \overline{PGM} pins are both high.

1.5 Erase Mode (U.V. Windowed Versions)

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000 μ W/cm² for approximately 20 minutes.

1.6 Programming Mode

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- VCC is brought to the proper voltage,
- VPP is brought to the proper V_H level,
- the \overline{CE} pin is low,
- the \overline{OE} pin is high, and
- the \overline{PGM} pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable, \overline{OE} is high, \overline{CE} is low and a low-going pulse on the \overline{PGM} line programs that location.

1.7 Verify

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- VCC is at the proper level,
- VPP is at the proper V_H level,
- the \overline{CE} line is low,
- the \overline{PGM} line is high, and
- the \overline{OE} line is low.

1.8 Inhibit

When programming multiple devices in parallel with different data, only \overline{CE} or \overline{PGM} need be under separate control to each device. By pulsing the \overline{CE} or \overline{PGM} line low on a particular device in conjunction with the \overline{PGM} or \overline{CE} line low, that device will be programmed; all other devices with \overline{CE} or \overline{PGM} held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on \overline{CE} or \overline{PGM}); and the device is inhibited from programming.

1.9 Identity Mode

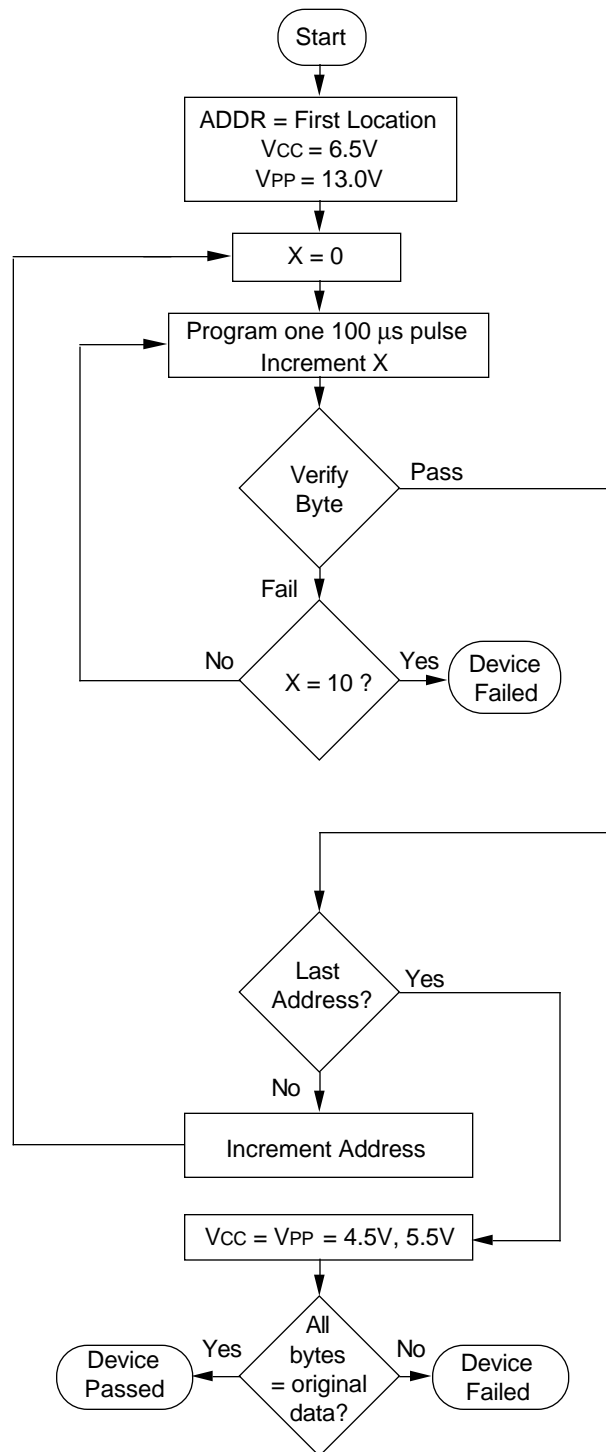
In this mode, specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to V_H (11.5V to 12.5V). The \overline{CE} and \overline{OE} lines must be at V_{IL} . A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin \rightarrow	Input	Output									
Identity \downarrow	A0	0	0	0	0	0	0	0	0	0	H e x
		7	6	5	4	3	2	1	0		
Manufacturer	V_{IL}	0	0	1	0	1	0	0	1		29
Device Type*	V_{IH}	0	0	0	0	0	0	1	0		02

* Code subject to change

FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM

Conditions:

 $T_{amb} = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$ $V_{CC} = 6.5 \pm 0.25\text{V}$ $V_{PP} = 13.0 \pm 0.25\text{V}$ 

NOTES:

NOTES:

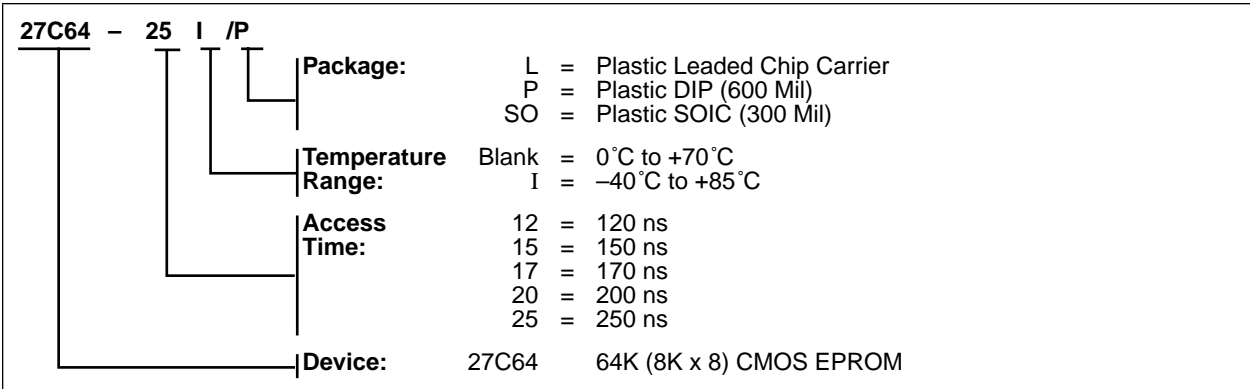
27C64

NOTES:

27C64

27C64 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.



WORLDWIDE SALES & SERVICE

AMERICAS

Corporate Office

Microchip Technology Inc.
2355 West Chandler Blvd.
Chandler, AZ 85224-6199
Tel: 602 786-7200 Fax: 602 786-7277
Technical Support: 602 786-7627
Web: <http://www.microchip.com>

Atlanta

Microchip Technology Inc.
500 Sugar Mill Road, Suite 200B
Atlanta, GA 30350
Tel: 770 640-0034 Fax: 770 640-0307

Boston

Microchip Technology Inc.
5 Mount Royal Avenue
Marlborough, MA 01752
Tel: 508 480-9990 Fax: 508 480-8575

Chicago

Microchip Technology Inc.
333 Pierce Road, Suite 180
Itasca, IL 60143
Tel: 708 285-0071 Fax: 708 285-0075

Dallas

Microchip Technology Inc.
14651 Dallas Parkway, Suite 816
Dallas, TX 75240-8809
Tel: 972 991-7177 Fax: 972 991-8588

Dayton

Microchip Technology Inc.
Suite 150
Two Prestige Place
Miamisburg, OH 45342
Tel: 513 291-1654 Fax: 513 291-9175

Los Angeles

Microchip Technology Inc.
18201 Von Karman, Suite 1090
Irvine, CA 92612
Tel: 714 263-1888 Fax: 714 263-1338

New York

Microchip Technology Inc.
150 Motor Parkway, Suite 416
Hauppauge, NY 11788
Tel: 516 273-5305 Fax: 516 273-5335

San Jose

Microchip Technology Inc.
2107 North First Street, Suite 590
San Jose, CA 95131
Tel: 408 436-7950 Fax: 408 436-7955

Toronto

Microchip Technology Inc.
5925 Airport Road, Suite 200
Mississauga, Ontario L4V 1W1, Canada
Tel: 905 405-6279 Fax: 905 405-6253

ASIA/PACIFIC

China

Microchip Technology
Unit 406 of Shanghai Golden Bridge Bldg.
2077 Yan'an Road West, Hongjiao District
Shanghai, Peoples Republic of China
Tel: 86 21 6275 5700
Fax: 011 86 21 6275 5060

Hong Kong

Microchip Technology
RM 3801B, Tower Two
Metroplaza
223 Hing Fong Road
Kwai Fong, N.T. Hong Kong
Tel: 852 2 401 1200 Fax: 852 2 401 3431

India

Microchip Technology
No. 6, Legacy, Convent Road
Bangalore 560 025 India
Tel: 91 80 526 3148 Fax: 91 80 559 9840

Korea

Microchip Technology
168-1, Youngbo Bldg. 3 Floor
Samsung-Dong, Kangnam-Ku,
Seoul, Korea
Tel: 82 2 554 7200 Fax: 82 2 558 5934

Singapore

Microchip Technology
200 Middle Road
#10-03 Prime Centre
Singapore 188980
Tel: 65 334 8870 Fax: 65 334 8850

Taiwan, R.O.C

Microchip Technology
10F-1C 207
Tung Hua North Road
Taipei, Taiwan, ROC
Tel: 886 2 717 7175 Fax: 886 2 545 0139

EUROPE

United Kingdom

Arizona Microchip Technology Ltd.
Unit 6, The Courtyard
Meadow Bank, Furlong Road
Bourne End, Buckinghamshire SL8 5AJ
Tel: 44 1628 850303 Fax: 44 1628 850178

France

Arizona Microchip Technology SARL
Zone Industrielle de la Bonde
2 Rue du Buisson aux Fraises
91300 Massy - France
Tel: 33 1 69 53 63 20 Fax: 33 1 69 30 90 79

Germany

Arizona Microchip Technology GmbH
Gustav-Heinemann-Ring 125
D-81739 Muenchen, Germany
Tel: 49 89 627 144 0 Fax: 49 89 627 144 44

Italy

Arizona Microchip Technology SRL
Centro Direzionale Colleone Pas Taurus 1
Viale Colleoni 1
20041 Agrate Brianza
Milan Italy
Tel: 39 39 6899939 Fax: 39 39 689 9883

JAPAN

Microchip Technology Intl. Inc.
Benex S-1 6F
3-18-20, Shin Yokohama
Kohoku-Ku, Yokohama
Kanagawa 222 Japan
Tel: 81 45 471 6166 Fax: 81 45 471 6122

9/3/96



MICROCHIP

All rights reserved. © 1996, Microchip Technology Incorporated, USA. 9/96



Printed on recycled paper.

Information contained in this publication regarding device applications and the like is intended through suggestion only and may be superseded by updates. No representation or warranty is given and no liability is assumed by Microchip Technology Incorporated with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any intellectual property rights. The Microchip logo and name are registered trademarks of Microchip Technology Inc. All rights reserved. All other trademarks mentioned herein are the property of their respective companies.

This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.